

PCF 5020 WP/A	CMOS- $\mu$ C-IC	hi-speed, Digital-Audio Signal-Proz.	52-PLCC	-	
PCF 8574(A)P	CMOS-IC	8-Bit I/O Expander, bidirekt. f. f'c	16-DIP	-	
PCF 8574(A)T	CMOS-IC	=PCF 8574(P): SMD	16-MDIP	-	
PD... (NEC)	...-IC	$\rightarrow$ $\mu$ PD....		$\rightarrow$ $\mu$ PD....	
PE 2 D,G	Si-Di	=EGP 20...		$\rightarrow$ EGP 20...	31a
PE 3100	Si-N	VHF, 30V, >500MHz	7	BF 959	7d
PE 4001	Si-N	=SE 4001	7	$\rightarrow$ SE 4001	
PE 4002	Si-N	=SE 4002	7	$\rightarrow$ SE 4002	
PE 4010	Si-N	=SE 4010: 0,625W	7e	$\rightarrow$ SE 4010	
PE 4020	Si-N	=SE 4020: 0,625W	7e	$\rightarrow$ SE 4020	
PE 5010	Si-N	AM/FM, 30V, >375MHz		BF 198, BF 255	7d
PE 5013	Si-N	AM/FM, 20V, >300MHz		BF 198, BF 255	7d
PE 5015	Si-N	AM/FM, 20V, >300MHz		BF 198, BF 255	7d
PE 6020	Si-N	=SE 6020	7	$\rightarrow$ SE 6020	
PE 6021	Si-N	=SE 6021	7	$\rightarrow$ SE 6021	
PE 6022	Si-N	=SE 6022	7	$\rightarrow$ SE 6022	
PE 7058	Si-N	Vid. 220/220V, 0,5A, 0,625W, >40MHz	7e	BF 420 A	7c
PE 7059	Si-N	=PE 7058: 300/300V	7e	BF 420 A	7c
PE 8050	Si-N	NF-Tr/E, 30V, 1,5A, >100MHz	7e	2SD1207	7c
PE 8051	Si-N	=PE 8050: 45V	7e	2SD1207	7c
PE 8052	Si-N	=PE 8050: 20V	7e	2SD1207	7c
PE 8550	Si-P	NF-Tr/E, 30V, 1,5A, >100MHz	7e	2SB892	7c(9mm)
PE 8551	Si-P	=PE 8550: 45V	7e	2SB892	7c(9mm)
PE 8552	Si-P	=PE 8550: 20V	7e	2SB892	7c(9mm)
PFR 305	Si-Di	GI, S, 50V, 3A, <50ns	31a	BYV 28/200	31a
PFR 310	Si-Di	=PFR 305: 100V	31a	BYV 28/200	31a
PFR 850	Si-Di	GI, S, 50V, 3A, <200ns	31a	BYW 95 C	31a
PFR 851	Si-Di	=PFR 850: 100V	31a	BYW 95 C	31a
PFR 852	Si-Di	=PFR 850: 200V	31a	BYW 95 C	31a
PFR 853	Si-Di	=PFR 850: 300V	31a	BYW 95 C	31a
PFR 854	Si-Di	=PFR 850: 400V	31a	BYW 95 C	31a
PFR 855	Si-Di	=PFR 850: 500V	31a	BYW 95 C	31a
PFR 856	Si-Di	=PFR 850: 600V	31a	BYW 95 C	31a
PH 2222(A)	Si-N	=2N2222(A): 0,625W	7a	$\rightarrow$ 2N2222(A)	
PH 2369	Si-N	=2N2369: 0,5W	7a	$\rightarrow$ 2N2369	
PH 2907(A)	Si-P	=2N2907: 0,625W	7a	$\rightarrow$ 2N2907(A)	
PH 2955(T)	Si-P	=TIP 2955	17j	(BD 250 C)	18j 6
PH 3055(T)	Si-N	=TIP 3055	17j	(BD 249 C)	18j 6
PH 5415	Si-P	=2N5415: 0,5W	7a	-	
PH 5416	Si-P	=2N5416: 0,5W	7a	-	
PH 13002	Si-N	=MJ 4360: 28W	14j	(BUX 85)	17j 4
PH 13003	Si-N	=MJ 4361: 28W	14j	(BUX 85)	17j 4
PHD 003	Opto	CD, Photodiode	8-MDIP	-	
PHD 010	Opto	Photodiode f. Magneto-Optical Disk	12-MDIP	-	
PIP 2250	CMOS-IC	CTV, PIP-Prozessor	68-PLCC	-	
PL 3V3Z...200Z	Z-Di	=BZY 97 C3V3...C200	31a	Z-Diode ....V	31a
PL 4001	Si-Di	$\rightarrow$ 1N4001	31a	1N4007	31a
PL 4002	Si-Di	$\rightarrow$ 1N4002	31a	1N4007	31a
PL 4003	Si-Di	$\rightarrow$ 1N4003	31a	1N4007	31a
PL 4004	Si-Di	$\rightarrow$ 1N4004	31a	1N4007	31a
PL 4005	Si-Di	$\rightarrow$ 1N4005	31a	1N4007	31a
PL 4006	Si-Di	$\rightarrow$ 1N4006	31a	1N4007	31a
PL 4007	Si-Di	$\rightarrow$ 1N4007	31a	1N4007	31a
PLE 0,7	Si-St	0,65...0,75V(5mA)	31a	(1N4148)	31a
PLE 1,5	Si-St	1,35...1,55V(5mA)	31a	Z-Diode 1,4V	31a
PLE 2	Si-St	1,9...2,2V(5mA)	31a	Z-Diode 2,1V	31a